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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/681,861	06/19/2001	Mathew L. Sommers	GLO 2 0054	7250	
27885	7590 12/19/2002				
FAY, SHARPE, FAGAN, MINNICH & MCKEE, LLP			EXAM	EXAMINER	
	1100 SUPERIOR AVENUE, SEVENTH FLOOR CLEVELAND, OH 44114			HARPER, HOLLY R	
	•		ART UNIT	PAPER NUMBER	
			2879		
				DATE MAILED: 12/19/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)	- Ih	
Office Action Summary		09/681,861	SOMMERS MATE	SOMMERS, MATHEW L.	
		Examiner	Art Unit		
		Holly R. Harper	2879		
	The MAILING DATE of this communica			dress	
I HE - Exte after - If the	ORTENED STATUTORY PERIOD FOR MAILING DATE OF THIS COMMUNICA nsions of time may be available under the provisions of 3 SIX (6) MONTHS from the mailing date of this communic period for reply specified above is less than thirty (30) days.	TION. 7 CFR 1.136(a). In no event, however ation. Its a reply within the statutory minim	er, may a reply be timely filed	,	
- ITNC - Failu - Any	period for reply is specified above, the maximum statutore to reply within the set or extended period for reply will, reply received by the Office later than three months after ed patent term adjustment. See 37 CFR 1.704(b).	ry period will apply and will expire SI. by statute, cause the application to be	X (6) MONTHS from the mailing date of this co	mmunication.	
1)	Responsive to communication(s) filed	on			
2a) <u></u> □	This action is FINAL . 2b)		al.		
3) <u> </u>	Since this application is in condition for closed in accordance with the practice on of Claims	allowance except for forr under <i>Ex parte Quayle</i> , 1	nal matters, prosecution as to the 935 C.D. 11, 453 O.G. 213.	e merits is	
4)🖂	Claim(s) 1-19 is/are pending in the app	lication.			
	4a) Of the above claim(s) <u>17-19</u> is/are w		on.		
	Claim(s) is/are allowed.				
6)⊠	Claim(s) 1-6,8 and 10-15 is/are rejected				
	Claim(s) <u>7,9 and 16</u> is/are objected to.				
	Claim(s) are subject to restriction	and/or election requireme	ent.		
	on Papers	•			
9) 🗌 🗆	The specification is objected to by the Ex	aminer.			
10)□ 7	he drawing(s) filed on is/are: a)[accepted or b) dojected	to by the Examiner.		
	Applicant may not request that any objection	n to the drawing(s) be held i	n abeyance. See 37 CFR 1.85(a).		
11) 🔲 🏻	he proposed drawing correction filed on	is: a) approved	b) disapproved by the Examine	r.	
	If approved, corrected drawings are require	d in reply to this Office action	1.		
12) 🔲 T	he oath or declaration is objected to by	he Examiner.			
Priority u	nder 35 U.S.C. §§ 119 and 120				
13) 🗌	Acknowledgment is made of a claim for	foreign priority under 35 U	.S.C. § 119(a)-(d) or (f).		
a)[All b) Some * c) None of:				
	1. ☐ Certified copies of the priority docu	uments have been receive	ed.		
:	2. Certified copies of the priority docu	ıments have been receive	d in Application No.		
	3. Copies of the certified copies of th application from the Internation ee the attached detailed Office action for	e priority documents have nal Bureau (PCT Rule 17.:	been received in this National S	tage	
	knowledgment is made of a claim for do			annlication)	
a)	☐ The translation of the foreign language cknowledgment is made of a claim for do	ge provisional application	has been received.	application).	
ttachment(Jour priority under 30 (33 120 dilu/01 121.		
) Notice) Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-9- ation Disclosure Statement(s) (PTO-1449) Paper N	18) 5) No	erview Summary (PTO-413) Paper No(s) tice of Informal Patent Application (PTO- eer:	152)	
Patent and Trac O-326 (Rev.	.	fice Action Summary	Part of P		

DETAILED ACTION

Election/Restrictions

- Restriction to one of the following inventions is required under 35 U.S.C. 121: 1.
 - I. Claims 1- 16, drawn to a light-emitting device classified in class 313, subclass 512.
 - Claims 17-19, drawn to method of manufacturing, classified in class 445, subclass II. 24.

The inventions are distinct, each from the other because of the following reasons:

Inventions II and I are related as process of making and product made. The inventions are distinct if either or both of the following can be shown: (1) that the process as claimed can be used to make other and materially different product or (2) that the product as claimed can be made by another and materially different process (MPEP § 806.05(f)). In the instant case the product as claimed could be made by another alternative process such as providing a frame with an uneven portions and positioning the phosphor embedded epoxy on the frame and then attaching the nitride compound on the phosphor.

Because these inventions are distinct for the reasons given above and have acquired a separate status in the art as shown by their different classification, restriction for examination purposes as indicated is proper.

During a telephone conversation with Scott McCollister on November 27, 2002 a provisional election was made without traverse to prosecute the invention of I, claims 1-16. Affirmation of this election must be made by applicant in replying to this Office action. Claims Art Unit: 2879

17-19 withdrawn from further consideration by the examiner, 37 CFR 1.142(b), as being drawn to a non-elected invention.

Claim Rejections - 35 USC § 102

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-16 are rejected under 35 U.S.C. 102(b) as being anticipated by Shimizu et al. (USPN 5,998,925) hereinafter "Shimizu."

In regard to claim 1, the Shimizu reference discloses a light-emitting device comprised of a nitride compound semiconductor (Column 3, Lines 26-27) providing blue emission (Column 4, Line 64). A coating material made of phosphor and epoxy is used to surround the nitride compound (Column 16, Lines 54-60 and Figure 1). The frame includes an uneven surface (Figure 1, element 105). In the uneven part of the frame, the nitride compound and epoxy are located.

In regard to claims 2-4, the Shimizu reference discloses that the nitride compound contains GaN (Column 4, Line 53), a binary compound in group III.

In regard to claim 5, the Shimizu reference discloses that a GaN compound semiconductor is made by forming a layer of InGaN on a substrate (Column 13, Line 60). This is surrounded by the epoxy (Figure 1).

In regard to claim 6, the Shimizu reference discloses that the use of a sapphire substrate is preferable (Column 14, Lines 9-10).

In regard to claim 8, the Shimizu reference discloses that the fluorescent material absorbs light of a short wavelength (blue light) and emits light of a long wavelength (Column 6, Lines 20-24), meaning visible light.

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In regard to claims 10 and 11, the Shimizu reference discloses a light-emitting device comprised of a nitride compound semiconductor (Column 3, Lines 26-27) providing blue emission (Column 4, Line 64). A coating material made of phosphor and epoxy is used to surround the nitride compound (Column 16, Lines 54-60 and Figure 1). The frame includes an uneven surface (Figure 1, element 105). In the uneven part of the frame, the nitride compound and epoxy are located. The fluorescent material absorbs light of a short wavelength (blue light) and emits light of a long wavelength (Column 6, Lines 20-24), meaning visible light.

In regard to claim 12, the Shimizu reference discloses the use of a phosphor that has two ranges of wavelengths. The range of the short wavelength being absorbed is 400 to 500 nm (Figure 3A) and the range of the long wavelength being emitted is 450 nm to 700 nm (Figure 3B).

In regard to claim 13, the Shimizu reference discloses a light-emitting device comprised of a nitride compound semiconductor (Column 3, Lines 26-27) providing blue emission (Column 4, Line 64). A nitride compound semiconductor is made by forming a layer of InGaN on a substrate (Column 13, Line 60). A coating material made of phosphor and epoxy is used to surround the nitride compound and substrate (Column 16, Lines 54-60 and Figure 1). The frame includes an uneven surface (Figure 1, element 105). In the uneven part of the frame, the nitride compound, substrate, and epoxy are located.

In regard to claim 14, the Shimizu reference discloses that the nitride compound contains GaN (Column 4, Line 53), a binary compound.

In regard to claim 15, the Shimizu reference discloses that the use of a sapphire substrate is preferable (Column 14, Lines 9-10).

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Allowable Subject Matter

Claims 7, 9, and 16 are objected to as being dependent upon a rejected base claim, but 3.

would be allowable if rewritten in independent form including all of the limitations of the base

claim and any intervening claims.

Contact Information

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Holly Harper whose telephone number is (703) 305-7908. The

examiner can normally be reached on Monday-Friday from 8:30 AM to 5:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Nimesh Patel, can be reached on (703) 305-4794. The fax phone number for the

organization where this application or proceeding is assigned is (703) 308-7382.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is (703) 308-0956.

Holly Harper Patent Examiner

Art Unit 2879

NIMESHKUMAR D. PATEL SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2800